

THTVS411

Transient Voltage Suppressor for I/O protection

General Description

THine THTVS Transient Voltage Suppressor family is designed to protect sensitive interconnect I/O from overvoltage caused by ESD (Electrostatic

discharge),CDE (Cable Discharge Events) and EFT (Electrical fast transients).

The THTVS411 single-channel TVS is low

capacitance ESD protection device which designed to protect sensitive CML, PECL LVDS physical layer for ASIC, FPGA, SOC, ASSP and Display port,HDMI,PCIe and USB3.0 standard I/O.

The THTVS411 have a small capacitance of 0.45pF (Typ) and working voltage of 4V Vrwm.

This allows to be used on circuits operating around up to 8GHz with signal integrity. They may be used to meet the ESD immunity requirements of IEC 61000-4-2.

The dynamic resistance is extremely low 0.12 Ohms (Typ) providing optimum protection of sensitive circuits.

The THTVS411 is designed to protect a single-end lines. For differential lines, two THTVS411s will be employed.

The THTVS411 is in a small 2-pin $0.6 \times 0.3 \times 0.25$ mm package. Low capacitance, small package, and high level of ESD protection will makes a flexible solution for high speed applications.

Features

- ESD protection IEC 61000-4-2(ESD) ±25kV(air), ±20kV(contact)
- Ultra-small package
- Protect one line
- Low capacitance: 0.45pF Typ
- Low dynamic resistance: 0.12 Ohm typ
- Operating voltage: Vrwm 4.0V
- Two pin package (0.6 x 0.3 x 0.25mm)
- Packaging: Tape and Reel

Applications

Applications for sensitive and high speed I/O protection as followed.

- FPGA/SoC/ASSP high Seed I/O.
- CML/PECL/LVDS physical layer
- HDMI/DVI/DisplayPort[™]
- PCIExpress /eSATA
- USB3.0/3.1
- V-by-One[®] HS
- Sensitive Sensor I/O
- Connector and cable I/F

Schematic and package Diagram





Pin Configuration



Package pin configuration (Top view)

Pin Description

Pin No	Туре	Description			
1	I	Input or Ground ^{*1}			
2	I	Input or Ground ^{*1}			

*1: Ground must be tied to the PCB ground plane. Low impedance connection required.

Absolute Maximum Rating

Parameter	Symbol	Value	Unit
Peak Pulse Power (tp = 1.2/50µs)	P _{Pk}	30	W
ESD per IEC 61000-4-2 (Air) ^{*1} ESD per IEC 61000-4-2 (Contact) ^{*1}	V _{ESD}	+/- 25 +/- 20	kV
Operating Junction Temperature	TJ	-40 to +125	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Notes.

*1: Measured with a 20dB attenuator, 50 Ohm scope input impedance, 2GHz bandwidth. ESD gun return path connected to ESD ground plane.



Electrical Characteristics ((\mathbf{T})	i = 25 °C)	
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Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	4.0	V
Reverse Breakdown Voltage	V _{BR}	l _t = 1mA	5.5	7.5	8.5	V
Reverse Leakage Current	I _R	$V_{RWM} = 4.0V$	-	-	50	nA
Holding Current	Ін	-	50	120	-	mA
Clamping Voltage*2	V _c	$\begin{array}{l} tp = 1.2/50 \mu s \ Open \\ Circuit, 8/20 \mu s \ Short \\ Circuit \ Combination \\ Waveform \\ V_S = 16V, R_S = 2\Omega \ , \\ I_{SC} = 8A \end{array}$	-	5	8	V
ESD Clamping Voltage*3	D Clamping Voltage ^{*3}	I=4A,tlp=0.2/100ns	-	4.5	-	
		I=16A,tlp=0.2/100ns	-	6	-	V
Dynamic Resistance *4	$R_{_{DYN}}$	tlp=0.2/100ns	-	0.12	-	Ω
Junction Capacitance	C _j	$V_R = 0V$, f = 1MHz,	-	0.45	0.55	pF

Notes

*2 Measured using a 1.2/50us voltage, 8/20us current combination waveform, RS = 8 Ohms. Clamping is defined as the peak voltage across the device after the device snaps back to a conducting state.

*3 Transmission Line Pulse Test (TLP) Settings tp = 100ns, tr = 0.2ns, TLP I and V averaging window: t1 = 70ns to t2 = 90ns. *4 Dynamic resistance calculated from I TLP = 4A to I TLP = 16A

TLP Current (A)

20

15

10

5

0

0

2



Typical Characteristics



ESD Clamping (8kV Contact per IEC 61000-4-2)

ESD Clamping (-8kV Contact per IEC 61000-4-2)



TLP Characteristic (Negative Pulse)



Clamping Characteristic

4

6

Clamping Voltage (V)

8

10



Capacitance vs. Reverse Voltage





Typical Characteristics



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Package



Unit: mm

Symbol	Items	Min.	Nom.	Max.	
А	Mounting Height	0.235	0.250	0.265	
A1	Standoff	0.000	0.010	0.050	
b	Terminal Width	0.200	0.220	0.240	
D	Body Length	0.580	0.600	0.620	
E	Body Width	0.280	0.300	0.320	
е	Pitch	0.355 BSC			
L	-	0.140	0.160	0.180	
aaa	Coplanarity		0.08		



Land Pattern



(Note)

Please carefully consider your SMT conditions (Material of substrate, Solder Composition, Reflow Condition and so on), and adjusts the Land Pattern at your own risk.



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